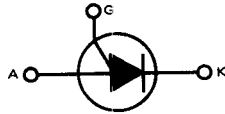


MPU131 (SILICON)

thru

MPU133

www.DataSheet4U.com



SILICON PROGRAMMABLE UNIUNCTION TRANSISTORS

... designed to enable the engineer to "program" unijunction characteristics such as R_{BB} , η , I_V , and I_P by merely selecting two resistor values. Application includes thyristor-trigger, oscillator, pulse and timing circuits. The MPU131, MPU132 and MPU133 may also be used in special thyristor applications due to the availability of an anode gate. Supplied in an inexpensive TO-92 plastic package for high-volume requirements, this package is readily adaptable for use in automatic insertion equipment.

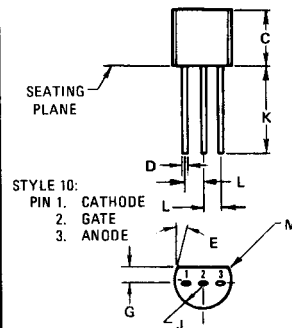
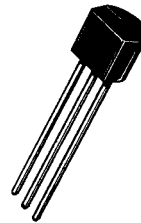
- Programmable — R_{BB} , η , I_V and I_P .
- Low On-State Voltage — 1.5 Volts Maximum @ $I_F = 50$ mA
- Low Gate to Anode Leakage Current — 5.0 nA Maximum
- High Peak Output Voltage — 11 Volts Typical
- Low Offset Voltage — 0.35 Volt Typical ($R_G = 10$ k ohms)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Dissipation Derate Above 25°C	P_F $1/\theta_{JA}$	375 5.0	mW mW/°C
DC Forward Anode Current Derate Above 25°C	I_T	200 2.67	mA mA/°C
DC Gate Current	I_G	±20	mA
Repetitive Peak Forward Current 100 μ s Pulse Width, 1.0% Duty Cycle 20 μ s Pulse Width, 1.0% Duty Cycle	I_{TRM}	1.0 2.0	Amp Amp
Non-Repetitive Peak Forward Current 10 μ s Pulse Width	I_{TSM}	5.0	Amp
Gate to Cathode Forward Voltage	V_{GKF}	40	Volt
Gate to Cathode Reverse Voltage	V_{GKR}	5.0	Volt
Gate to Anode Reverse Voltage	V_{GAR}	40	Volt
Anode to Cathode Voltage	V_{AK}	±40	Volt
Operating Junction Temperature Range	T_J	-50 to +100	°C
Storage Temperature Range	T_{stg}	-65 to +150	°C

SILICON PROGRAMMABLE UNIUNCTION TRANSISTORS

40 VOLTS
375 mW

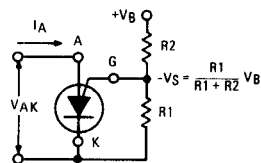
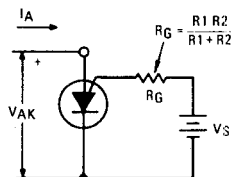
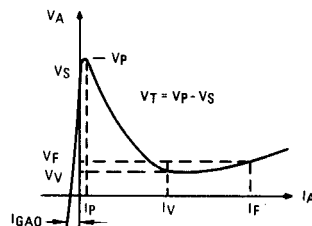
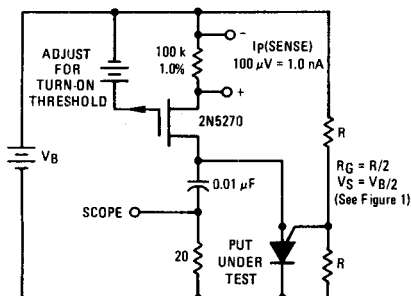
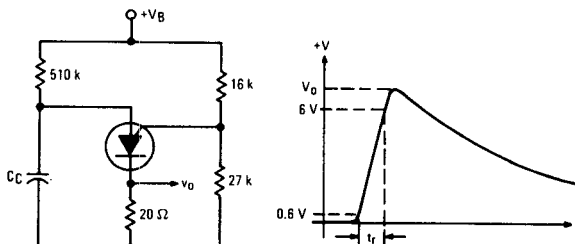


	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
C	4.450	4.700	0.175	0.185
D	0.407	0.482	0.016	0.019
E	5 ⁹ NOM		5 ⁹ NOM	
G	1.150	1.390	0.045	0.055
J	2.160	2.420	0.085	0.095
K	12.700	—	0.500	—
L	1.270 TP		0.050 TP	
M	0.076	0.330	0.003	0.013

CASE 29-01

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Peak Current ($V_S = 10\text{ Vdc}$, $R_G = 1.0\text{ M}\Omega$)	MPU131 MPU132 MPU133	I_P	—	1.25	2.0	μA
	MPU131		—	0.19	0.30	
	MPU132		—	0.08	0.15	
($V_S = 10\text{ Vdc}$, $R_G = 10\text{ k ohms}$)	MPU131		—	4.0	5.0	
	MPU132 MPU133		—	1.20 0.70	2.0 1.0	
Offset Voltage ($V_S = 10\text{ Vdc}$, $R_G = 1.0\text{ M}\Omega$)	MPU131 MPU132 MPU133	V_T	0.2	0.70	1.6	Volts
	MPU131		0.2	0.50	0.6	
	MPU132		0.2	0.40	0.6	
	MPU133		0.2	0.35	0.6	
($V_S = 10\text{ Vdc}$, $R_G = 10\text{ k ohms}$) (All Types)			0.2			
Valley Current ($V_S = 10\text{ Vdc}$, $R_G = 1.0\text{ M}\Omega$)	MPU131, 132 MPU133	I_V	—	18	50	μA
	MPU131		—	18	25	
	MPU132		70	270	—	
	MPU133		50	270	—	
($V_S = 10\text{ Vdc}$, $R_G = 10\text{ k ohms}$)						
Gate to Anode Leakage Current ($V_S = 40\text{ Vdc}$, $T_A = 25^\circ\text{C}$, Cathode Open)	—	I_{GAO}	—	1.0	5.0	nA
($V_S = 40\text{ Vdc}$, $T_A = 75^\circ\text{C}$, Cathode Open)			—	30	75	
Gate to Cathode Leakage Current ($V_S = 40\text{ Vdc}$, Anode to Cathode Shorted)	—	I_{GKS}	—	5.0	50	nA
Forward Voltage ($I_F = 50\text{ mA Peak}$)	1,6	V_F	—	0.8	1.5	Volts
Peak Output Voltage ($V_B = 20\text{ Vdc}$, $C_C = 0.2\text{ }\mu\text{F}$)	3,7	V_O	6.0	11	—	Volts
Pulse Voltage Rise Time ($V_B = 20\text{ Vdc}$, $C_C = 0.2\text{ }\mu\text{F}$)	3	t_r	—	40	80	ns

FIGURE 1 – ELECTRICAL CHARACTERIZATION**1A – PROGRAMMABLE UNIJUNCTION WITH "PROGRAM" RESISTORS R_1 and R_2** **1B – EQUIVALENT TEST CIRCUIT FOR FIGURE 1A USED FOR ELECTRICAL CHARACTERISTICS TESTING (ALSO SEE FIGURE 2)****1C – ELECTRICAL CHARACTERISTICS****FIGURE 2 – PEAK CURRENT (I_P) TEST CIRCUIT****FIGURE 3 – V_O AND t_r TEST CIRCUIT**

TYPICAL VALLEY CURRENT BEHAVIOR

FIGURE 4 – EFFECT OF SUPPLY VOLTAGE

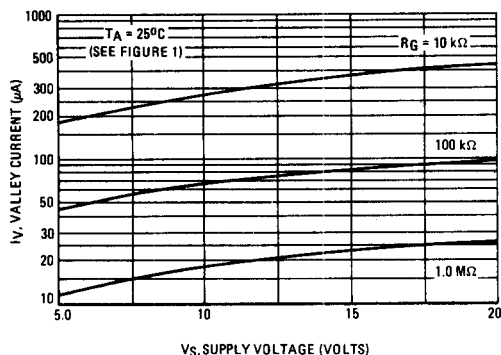


FIGURE 5 – EFFECT OF TEMPERATURE

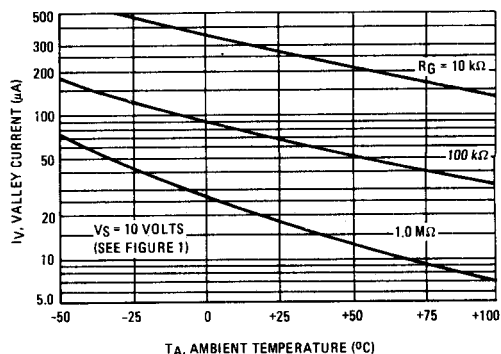


FIGURE 6 – FORWARD VOLTAGE

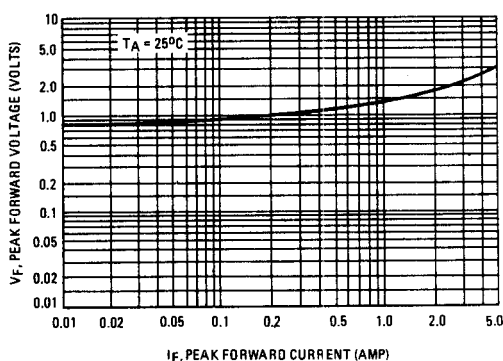


FIGURE 7 – PEAK OUTPUT VOLTAGE

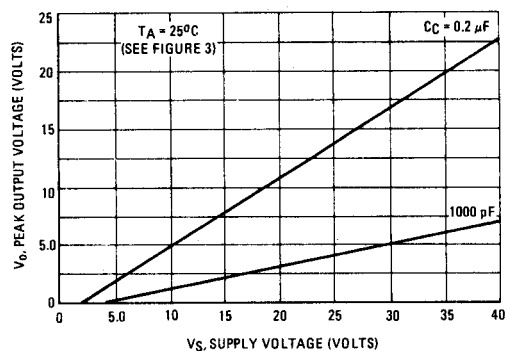
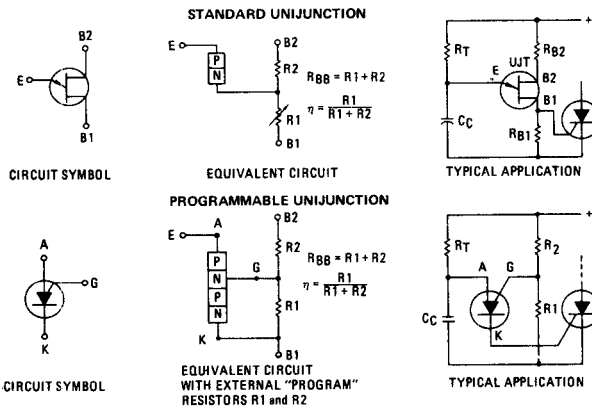
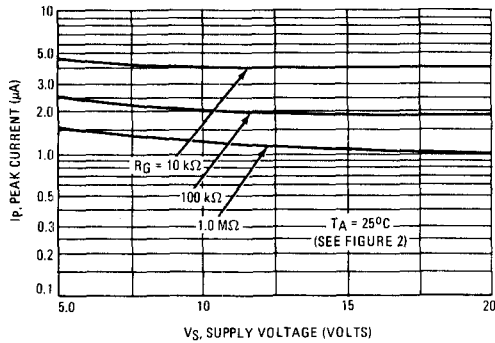
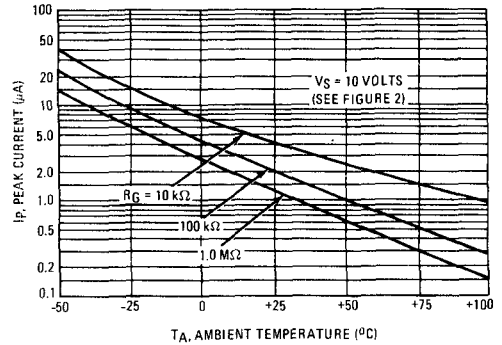


FIGURE 8 – STANDARD UNIJUNCTION COMPARED TO PROGRAMMABLE UNIJUNCTION

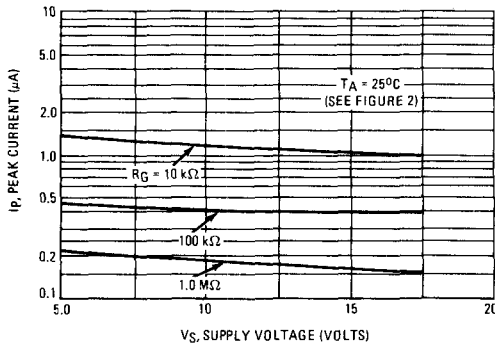
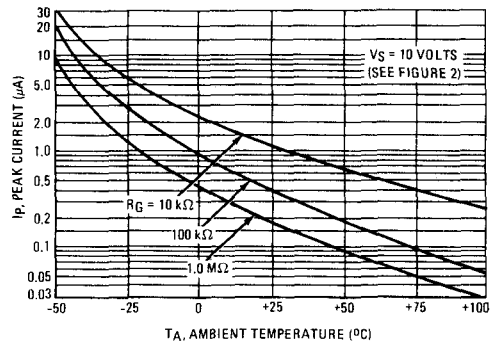


TYPICAL PEAK CURRENT BEHAVIOR

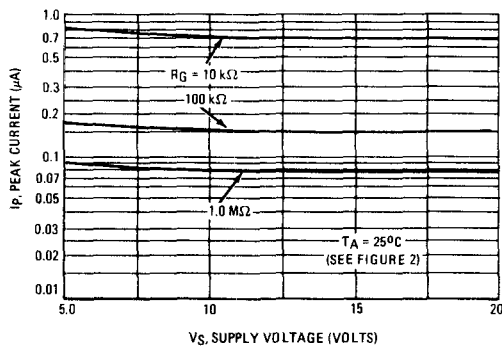
MPU131

FIGURE 9 – EFFECT OF SUPPLY VOLTAGE AND R_G FIGURE 10 – EFFECT OF TEMPERATURE AND R_G 

MPU132

FIGURE 11 – EFFECT OF SUPPLY VOLTAGE AND R_G FIGURE 12 – EFFECT OF TEMPERATURE AND R_G 

MPU133

FIGURE 13 – EFFECT OF SUPPLY VOLTAGE AND R_G FIGURE 14 – EFFECT OF TEMPERATURE AND R_G 